

RAD-TOLERANT CLASS V, WIDEBAND OPERATIONAL AMPLIFIER

FEATURES

- **Wide Bandwidth: 1 GHz**
- **Minimum Gain of 2 V/V (6 dB)**
- **High Slew Rate: 800 V/ μ s**
- **Low Voltage Noise: 2.4 nV/ $\sqrt{\text{Hz}}$**
- **Single Supply: 5 V, 3 V**
- **Quiescent Current: 18 mA**
- **Rad-Tolerant: 150 kRad (Si) TID**
- **QML-V Qualified, SMD 5962-07219**

APPLICATIONS

- **Active Filter**
- **ADC Driver**
- **Ultrasound**
- **Gamma Camera**
- **RF/Telecom**

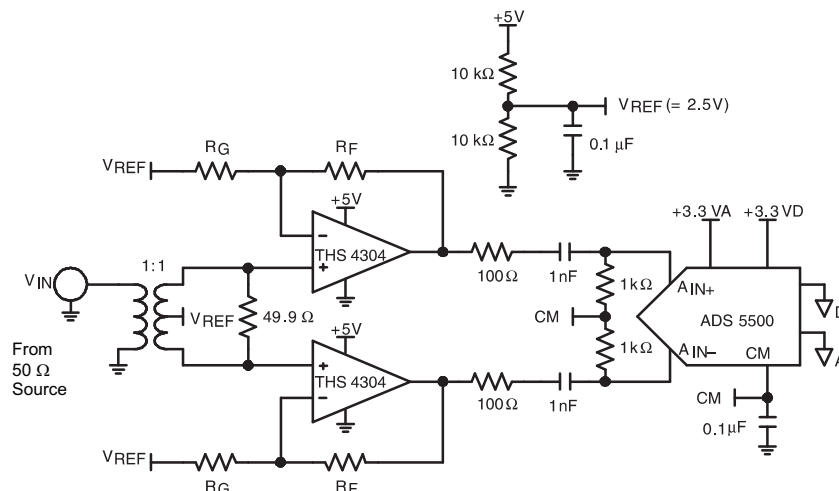
DESCRIPTION/ORDERING INFORMATION

The THS4304 is a wideband, voltage-feedback operational amplifier designed for use in high-speed analog signal processing chains operating with a single 5 V power supply. Developed in the BiCom3 silicon germanium process technology, the THS4304 offers best-in-class performance using a single 5 V supply as opposed to previous generations of operational amplifiers requiring ± 5 V supplies.

The THS4304 is a traditional voltage-feedback topology that provides the following benefits: balanced inputs, low offset voltage and offset current, low offset drift, high common mode and power supply rejection ratio.

The THS4304 is offered in 10-pin ceramic flatpack (U) and is specified over the full military temperature range, -55°C to 125°C .

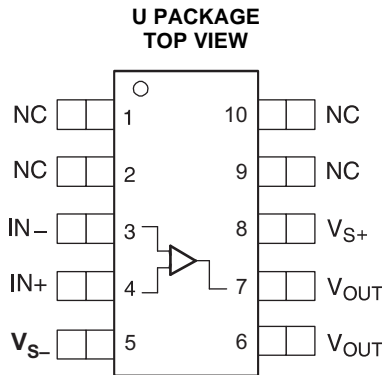
DIFFERENTIAL ADC DRIVE



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



NC – No internal connection

ORDERING INFORMATION⁽¹⁾

| PACKAGED DEVICES | PACKAGE TYPE ⁽²⁾ | PACKAGE MARKINGS | TRANSPORT MEDIA, QUANTITY |
|------------------|-----------------------------|------------------|---------------------------|
| 5962-0721901VHA | Ceramic Flatpack | 0721901VHA | Tubes, 25 |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

DISSIPATION RATINGS

| PACKAGE | θ_{JC} (°C/W) | θ_{JA} (°C/W) | POWER RATING ⁽¹⁾ | | |
|---------|-------------------------|-------------------------|-----------------------------|--------------------------|---------------------------|
| | | | $T_A \leq 25^\circ\text{C}$ | $T_A = 85^\circ\text{C}$ | $T_A = 125^\circ\text{C}$ |
| U (10) | 14.7 | 189 | 661 mW | 344 mW | 132 mW |

- (1) Power rating determined for a maximum junction temperature of 150°C. However, distortion starts to substantially increase above 125°C. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance and long-term reliability.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | UNIT |
|------------------------------|--|------------------------------|
| V_S | Supply voltage | +6.0 V |
| V_I | Input voltage | $\pm V_S$ |
| I_O | Output current | 150 mA |
| V_{ID} | Differential input voltage | ± 2 V |
| Continuous power dissipation | | See Dissipation Rating Table |
| T_J | Maximum junction temperature, any condition ⁽²⁾ | 150°C |
| T_{stg} | Storage temperature range | -65°C to 150°C |
| ESD Ratings | HBM | 1600 V |
| | CDM | 1000 V |
| | MM | 100 V |

- (1) The absolute maximum ratings under any condition is limited by the constraints of the silicon process. Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|---|---------------|----------------|----------------|------|
| Supply voltage, (V_{S+} and V_{S-}) | Dual supply | ± 1.35 | ± 2.5 | V |
| | Single supply | 2.7 | 5 | |
| Input common-mode voltage range | | $V_{S-} - 0.2$ | $V_{S+} + 0.2$ | V |

ELECTRICAL CHARACTERISTICS (Unchanged after 150 kRad)

 Specifications: $V_S = 5$ V: $R_F = 249 \Omega$, $R_L = 100 \Omega$, and $G = +3$ unless otherwise noted

| PARAMETER | CONDITIONS | TYP | OVER TEMPERATURE | | | | |
|--|--|----------------------|------------------|----------------|------------------------|---------|-----|
| | | 25°C | 25°C | -55°C to 125°C | UNITS | MIN/MAX | |
| AC PERFORMANCE | | | | | | | |
| Small-Signal Bandwidth | $G = +2$, $V_O = 100$ mVpp | 1 | | | GHz | Typ | |
| | $G = +3$, $V_O = 100$ mVpp | 800 | | | MHz | Typ | |
| | $G = +5$, $V_O = 100$ mVpp | 220 | | | MHz | Typ | |
| Gain Bandwidth Product | $G > +5$ | 1 | | | GHz | Typ | |
| 0.1 dB Flat Bandwidth | $G = +3$, $V_O = 100$ mVpp, $C_F = 0$ pF | 100 | | | MHz | Typ | |
| Large-Signal Bandwidth | $G = +3$, $V_O = 2 V_{PP}$ | 290 | | | MHz | Typ | |
| Slew Rate | $G = +3$, $V_O = 2$ -V Step | 800 | | | V/ μ s | Typ | |
| Settling Time to 1% | $G = +3$, $V_O = 2$ -V Step | 11 | | | ns | Typ | |
| Rise/Fall Times | $G = +3$, $V_O = 2$ -V Step | 2.5 | | | ns | Typ | |
| Harmonic Distortion | | | | | | | |
| Second Harmonic Distortion | $G = +3$, $V_O = 2 V_{PP}$, $f = 10$ MHz | $R_L = 100 \Omega$ | -67 | | | dBc | Typ |
| | | $R_L = 1$ k Ω | -85 | | | dBc | Typ |
| Third Harmonic Distortion | | $R_L = 100 \Omega$ | -100 | | | dBc | Typ |
| | | $R_L = 1$ k Ω | -85 | | | dBc | Typ |
| Third-Order Intermodulation Distortion (IMD ₃) | $G = +3$, $V_O = 2$ -V _{PP} envelope, 200 kHz tone spacing, $f = 20$ MHz | | -80 | | | dBc | Typ |
| Third-Order Output Intercept (OIP ₃) | | | 41 | | | dBm | Typ |
| Noise Figure | $G = +2$, $f = 1$ GHz | 15 | | | dB | Typ | |
| Input Voltage Noise | $f = 1$ MHz | 2.4 | | | nV/ $\sqrt{\text{Hz}}$ | Typ | |
| Input Current Noise | $f = 1$ MHz | 2.1 | | | pA/ $\sqrt{\text{Hz}}$ | Typ | |

ELECTRICAL CHARACTERISTICS (Unchanged after 150 kRad)Specifications: $V_S = \pm 2.5\text{ V}$, $V_{CM} = 0\text{ V}$, $R_L = 500\ \Omega$ unless otherwise noted

| PARAMETER | CONDITIONS | TYP | OVER TEMPERATURE | | | | |
|-------------------------------------|---|-----------|------------------|----------------|------------------------------|----------------------------|-----|
| | | 25°C | 25°C | -55°C to 125°C | UNITS | MIN/ MAX | |
| DC PERFORMANCE | | | | | | | |
| Open-Loop Voltage Gain (A_{OL}) | $V_O = \pm 0.8\text{ V}$ | 58 | 54 | 49 | dB | Min | |
| Input Offset Voltage | $V_O = 0\text{ V}$ | 0.5 | 4 | 6 | mV | Max | |
| Input Offset Voltage Drift | | | | 5 | $\mu\text{V}/^\circ\text{C}$ | Typ | |
| Input Bias Current | | | 7 | 12 | 20 | μA | Max |
| Input Bias Current Drift | | | | | 50 | $\text{nA}/^\circ\text{C}$ | Typ |
| Input Offset Current | | | 0.5 | 1 | 1.5 | μA | Max |
| Input Offset Current Drift | | | | | 10 | $\text{nA}/^\circ\text{C}$ | Typ |
| INPUT CHARACTERISTICS | | | | | | | |
| Common-Mode Input Range | | ± 2.7 | ± 2.3 | ± 2 | V | Min | |
| Common-Mode Rejection Ratio | $V_O = 0\text{ V}$, $V_{CM} = \pm 1\text{ V}$ | 86 | 78 | 52 | dB | Min | |
| Input Resistance | Each input, referenced to GND | 100 | | | k Ω | Typ | |
| Input Capacitance | | | 1.5 | | | pF | Typ |
| OUTPUT CHARACTERISTICS | | | | | | | |
| Output Voltage Swing | $R_L = 100\ \Omega$ | ± 1.4 | ± 1.3 | ± 1.15 | V | Min | |
| | $R_L = 1\text{ k}\Omega$ | ± 1.5 | ± 1.4 | ± 1.25 | | | |
| Output Current (Sourcing) | $R_L = 10\ \Omega$ | 98 | 80 | 70 | mA | Min | |
| Output Current (Sinking) | $R_L = 10\ \Omega$ | 95 | 70 | 55 | mA | Min | |
| Output Impedance | $f = 100\text{ kHz}$ | 0.016 | | | Ω | Typ | |
| POWER SUPPLY | | | | | | | |
| Maximum Operating Voltage | | ± 2.5 | ± 2.75 | ± 2.75 | V | Max | |
| Minimum Operating Voltage | | ± 2.5 | ± 1.35 | ± 1.35 | | Min | |
| Maximum Quiescent Current | $I_O = 0\text{ mA}$ | 18 | 18.9 | 19.7 | mA | Max | |
| Minimum Quiescent Current | $I_O = 0\text{ mA}$ | 18 | 17.5 | 16.0 | mA | Min | |
| Power Supply Rejection (+PSRR) | $V_{S+} = 3\text{ V}$ to 2 V , $V_{S-} = -2.5\text{ V}$ | 78 | 72 | 64 | dB | Min | |
| Power Supply Rejection (-PSRR) | $V_{S+} = 2.5\text{ V}$, $V_{S-} = -2\text{ V}$ to -3 V | 60 | 57 | 53 | dB | Min | |

ELECTRICAL CHARACTERISTICS (Unchanged after 150 kRad)

 Specifications: $V_S = 3\text{ V}$; $R_F = 249\ \Omega$, $R_L = 500\ \Omega$, and $G = +3$ unless otherwise noted

| PARAMETER | CONDITIONS | TYP | OVER TEMPERATURE | | | | |
|----------------------------|--|---------------------|------------------|----------------|------------------------|-------------|-----|
| | | 25°C | 25°C | -55°C to 125°C | UNITS | MIN/ MAX | |
| AC PERFORMANCE | | | | | | | |
| Small-Signal Bandwidth | $G = +2$, $V_O = 100\text{ mVpp}$ | 1 | | | GHz | Typ | |
| | $G = +5$, $V_O = 100\text{ mVpp}$ | 230 | | | MHz | Typ | |
| Gain Bandwidth Product | $G > +5$ | 1 | | | GHz | Typ | |
| Slew Rate | $G = +3$, $V_O = 1\text{-V Step}$ | 675 | | | V/ μs | Typ | |
| Rise/Fall Times | $G = +3$, $V_O = 0.5\text{-V Step}$ | 1.5 | | | ns | Typ | |
| HARMONIC DISTORTION | | | | | | | |
| Second Harmonic Distortion | $G = +3$, $V_O = 0.5\text{ V}_{PP}$, $f = 10\text{ MHz}$ | $R_L = 499\ \Omega$ | -82 | | | dBc | Typ |
| Third Harmonic Distortion | | | -82 | | | dBc | Typ |
| Noise Figure | $G = +2$, $f = 1\text{ GHz}$ | 15 | | | dB | Typ | |
| Input Voltage Noise | $f = 1\text{ MHz}$ | 2.4 | | | nV/ $\sqrt{\text{Hz}}$ | Typ | |
| Input Current Noise | $f = 1\text{ MHz}$ | 2.1 | | | pA/ $\sqrt{\text{Hz}}$ | Typ | |

ELECTRICAL CHARACTERISTICS (Unchanged after 150 kRad)

Specifications: $V_S = \pm 1.5\text{ V}$, $V_{CM} = 0\text{ V}$, $R_L = 500\ \Omega$ unless otherwise noted

| PARAMETER | CONDITIONS | TYP | OVER TEMPERATURE | | | |
|-------------------------------------|--|-----------|------------------|----------------|------------------------------|-------------|
| | | 25°C | 25°C | -55°C to 125°C | UNITS | MIN/ MAX |
| DC PERFORMANCE | | | | | | |
| Open-Loop Voltage Gain (A_{OL}) | $V_O = \pm 0.3\text{ V}$ | 57 | 52 | 50 | dB | Min |
| Input Offset Voltage | $V_O = 0\text{ V}$ | 1 | 4 | 6 | mV | Max |
| Input Offset Voltage Drift | | | | 5 | $\mu\text{V}/^\circ\text{C}$ | Typ |
| Input Bias Current | | 6 | 12 | 20 | μA | Max |
| Input Bias Current Drift | | | | 50 | $\text{nA}/^\circ\text{C}$ | Typ |
| Input Offset Current | | 0.4 | 1 | 1.5 | μA | Max |
| Input Offset Current Drift | | | | 10 | $\text{nA}/^\circ\text{C}$ | Typ |
| INPUT CHARACTERISTICS | | | | | | |
| Common-Mode Input Range | | ± 1.7 | ± 1.3 | ± 1 | V | Min |
| Common-Mode Rejection Ratio | $V_O = 0\text{ V}$, $V_{CM} = \pm 0.3\text{ V}$ | 68 | 62 | 50 | dB | Min |
| Input Resistance | Each input, referenced to GND | 100 | | | k Ω | Typ |
| Input Capacitance | | 1.5 | | | pF | Typ |
| OUTPUT CHARACTERISTIC | | | | | | |
| Output Voltage Swing | $R_L = 100\ \Omega$ | ± 0.4 | ± 0.3 | ± 0.2 | V | Min |
| | $R_L = 1\text{ k}\Omega$ | ± 0.5 | ± 0.4 | ± 0.3 | | |
| Output Current (Sourcing) | $R_L = 10\ \Omega$ | 30 | 25 | 20 | mA | Min |
| Output Current (Sinking) | $R_L = 10\ \Omega$ | 32 | 27 | 21 | mA | Min |
| Output Impedance | $f = 100\text{ kHz}$ | 0.016 | | | Ω | Typ |
| POWER SUPPLY | | | | | | |
| Maximum Operating Voltage | | ± 1.5 | ± 2.75 | ± 2.75 | V | Max |
| Minimum Operating Voltage | | ± 1.5 | ± 1.35 | ± 1.35 | | Min |
| Maximum Quiescent Current | $I_O = 0\text{ mA}$ | 17.2 | 17.9 | 18.6 | mA | Max |
| Minimum Quiescent Current | $I_O = 0\text{ mA}$ | 17.2 | 16.5 | 15.0 | mA | Min |
| Power Supply Rejection (+PSRR) | $V_{S+} = 1.8\text{ V to } 1.2\text{ V}$, $V_{S-} = -1.5\text{ V}$ | 80 | 60 | 53 | dB | Min |
| Power Supply Rejection (-PSRR) | $V_{S+} = 1.5\text{ V}$, $V_{S-} = -1.2\text{ V to } -1.8\text{ V}$ | 60 | 55 | 52 | dB | Min |

TYPICAL CHARACTERISTICS
Table of Graphs

| | | FIGURE |
|--|------------------------------|-------------------|
| 5 V | | |
| Frequency Response | | 1 through 3, 5, 6 |
| 0.1 dB Flatness | | 4 |
| S-Parameters | vs Frequency | 7 |
| 2nd Harmonic Distortion | vs Frequency | 8, 10 |
| 3rd Harmonic Distortion | vs Frequency | 9, 11 |
| Harmonic Distortion | vs Output voltage | 12 |
| IMD ₃ 3rd Order Intermodulation Distortion | vs Frequency | 13 |
| OIP ₃ 3rd Order Output Intercept Point | vs Frequency | 14 |
| SR Slew Rate | vs Output voltage | 15 |
| V _n /I _n Noise | vs Frequency | 16 |
| Noise Figure | vs Frequency | 17 |
| I _q Quiescent Current | vs Supply voltage | 18 |
| Rejection Ratio | vs Frequency | 19 |
| V _O Output Voltage | vs Load resistance | 20 |
| V _{OS} Input Offset Voltage | vs Input common-mode voltage | 21 |
| I _{IB} /I _{IO} Input Bias and Offset Current | vs Case temperature | 22 |
| V _{OS} Input Offset Voltage | vs Case temperature | 23 |
| V _O Small-signal Transient Response | | 24 |
| V _O Large-signal Transient Response | | 25 |
| V _O Settling Time | | 26 |
| V _O Overdrive Recovery Time | | 27 |
| 3 V | | |
| Frequency Response | | 28 through 30 |
| Harmonic Distortion | vs Frequency | 31 |
| Harmonic Distortion | vs Output voltage | 32 |
| SR Slew Rate | vs Output voltage | 33 |
| V _O Output Voltage | vs Load resistance | 34 |
| I _{IB} /I _{IO} Input Bias and Offset Current | vs Case temperature | 35 |
| V _{OS} Input Offset Voltage | vs Case temperature | 36 |

TYPICAL CHARACTERISTICS (5 V)

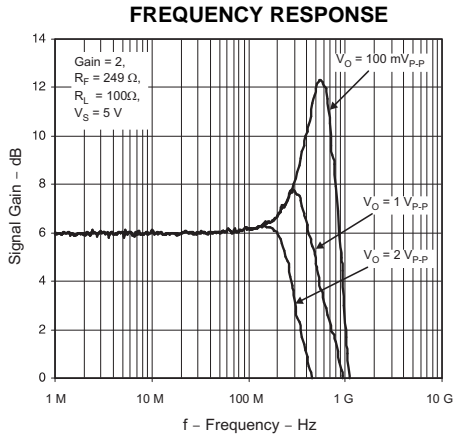


Figure 1.

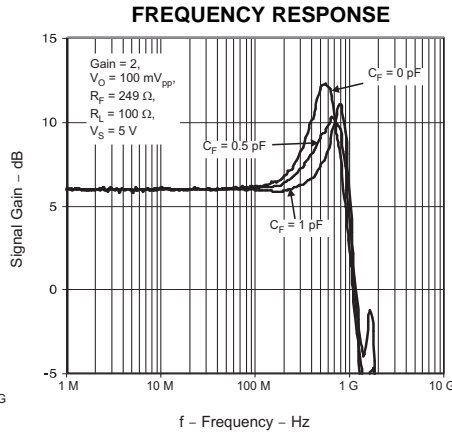


Figure 2.

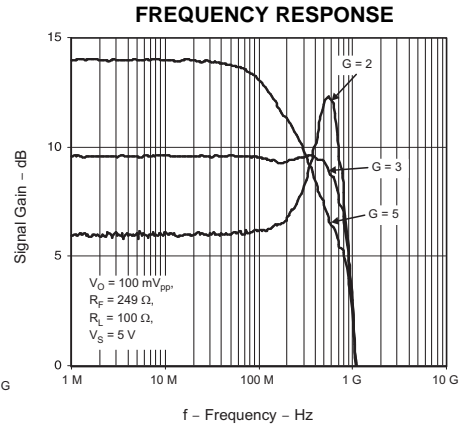


Figure 3.

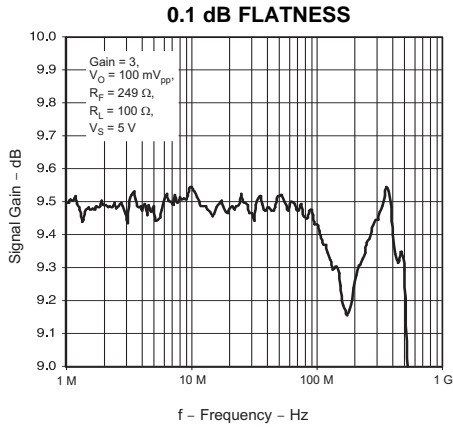


Figure 4.

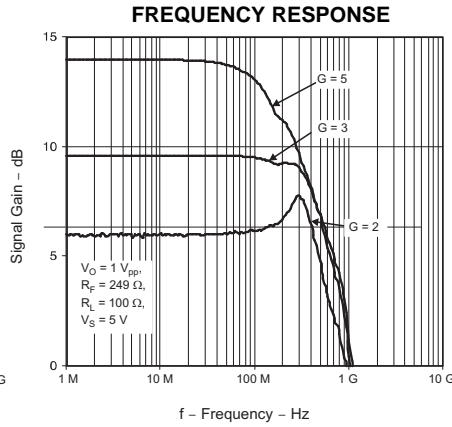


Figure 5.

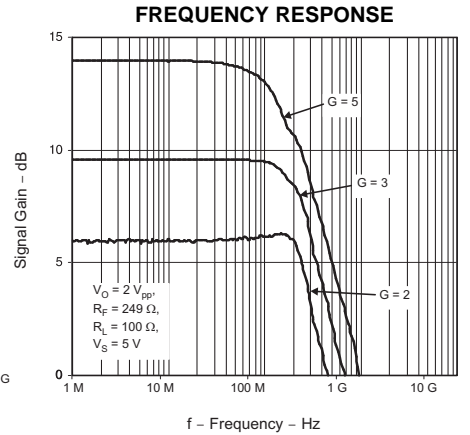


Figure 6.

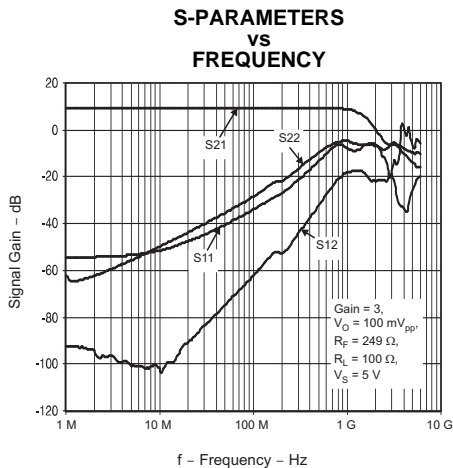


Figure 7.

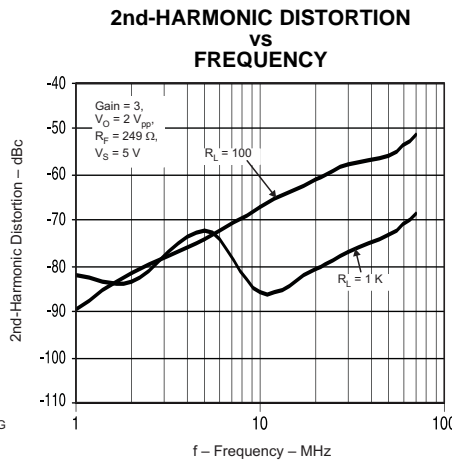


Figure 8.

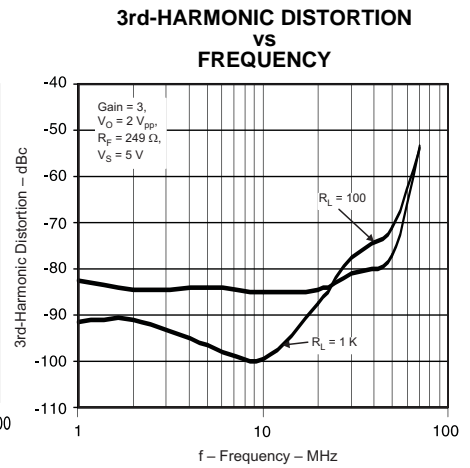


Figure 9.

TYPICAL CHARACTERISTICS (5 V) (continued)

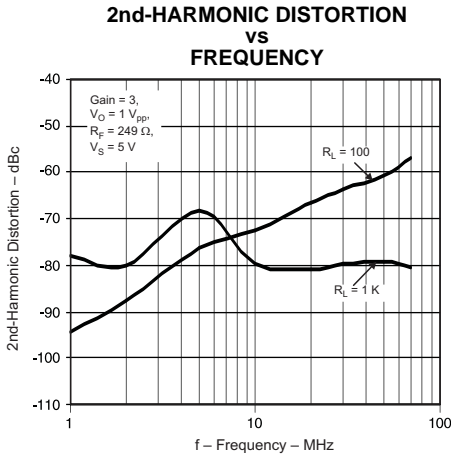


Figure 10.

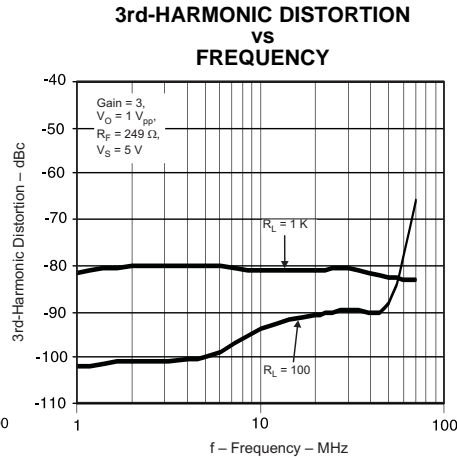


Figure 11.

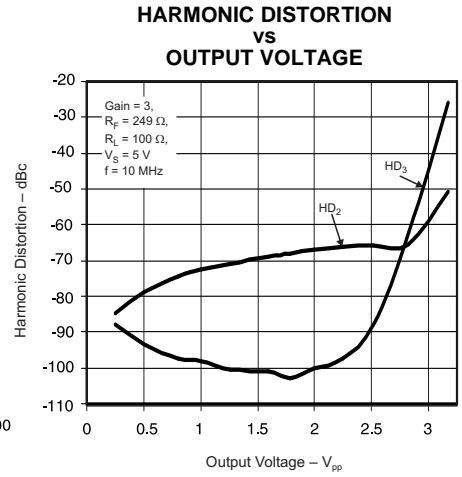


Figure 12.

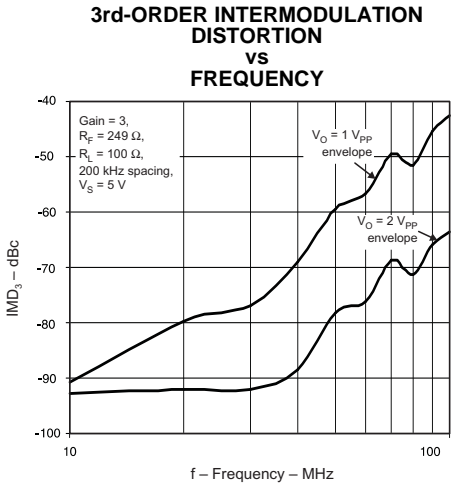


Figure 13.

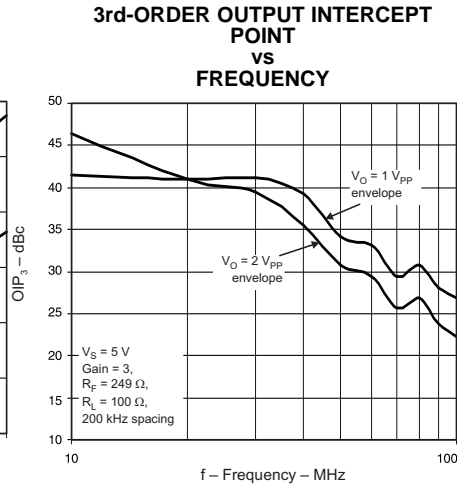


Figure 14.

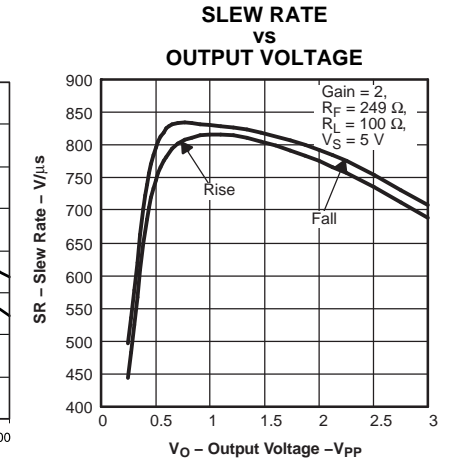


Figure 15.

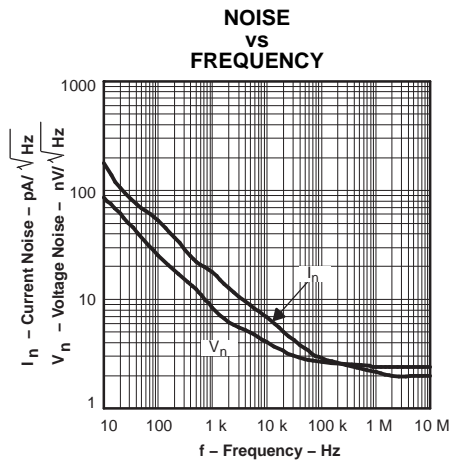


Figure 16.

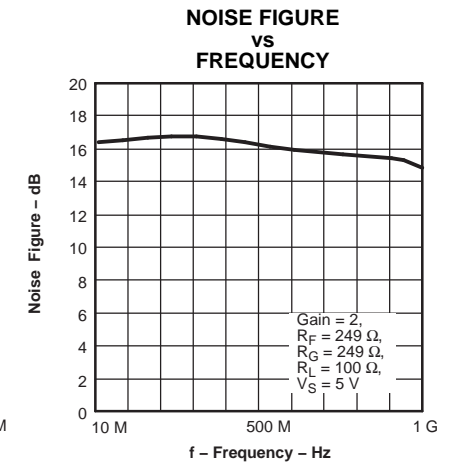


Figure 17.

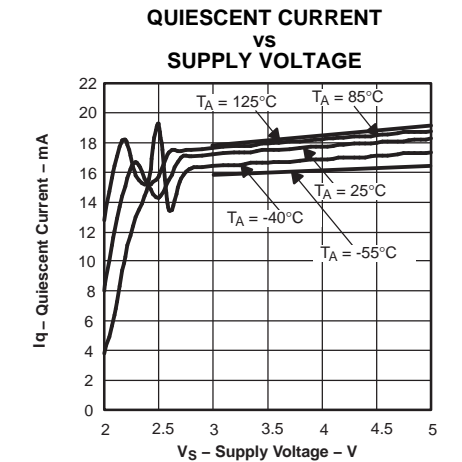


Figure 18.

TYPICAL CHARACTERISTICS (5 V) (continued)

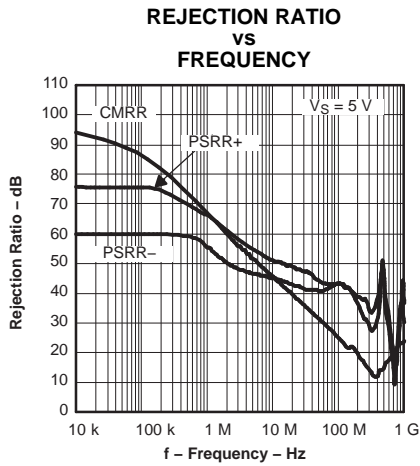


Figure 19.

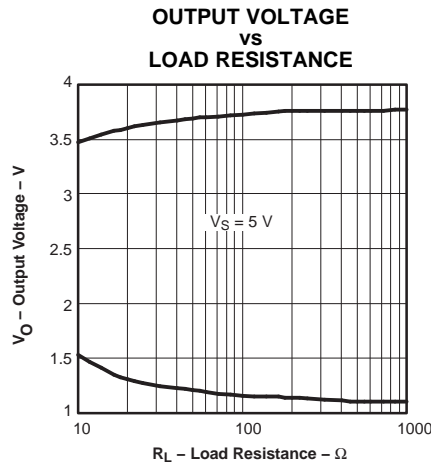


Figure 20.

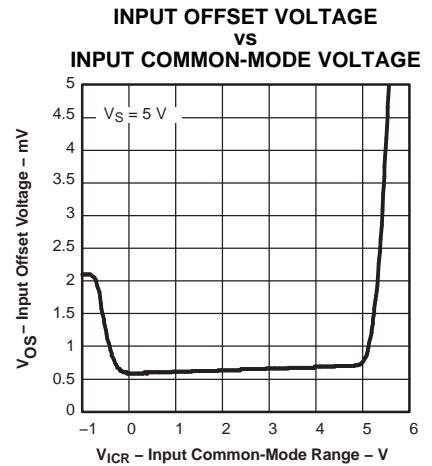


Figure 21.

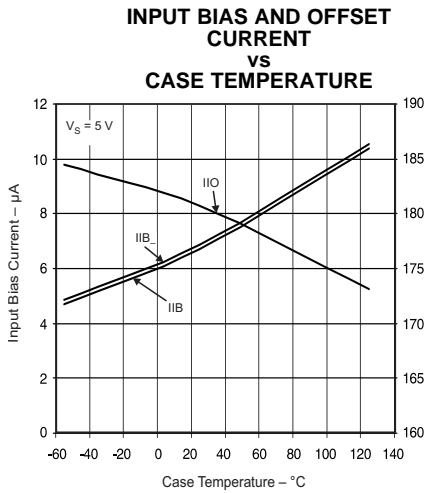


Figure 22.

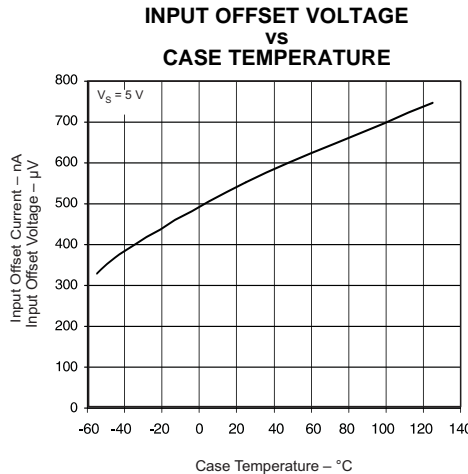


Figure 23.

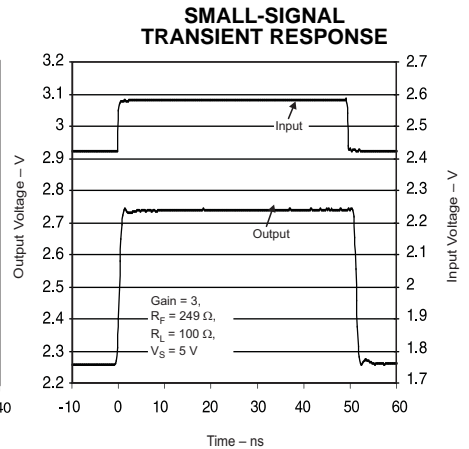


Figure 24.

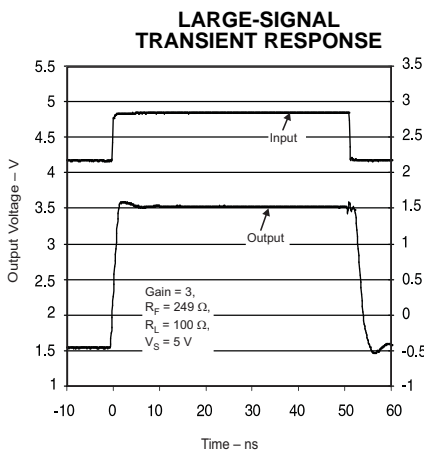


Figure 25.

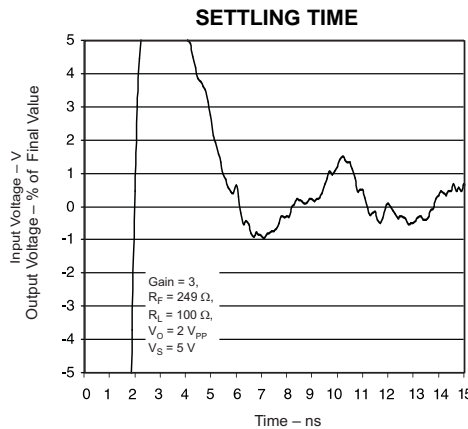


Figure 26.

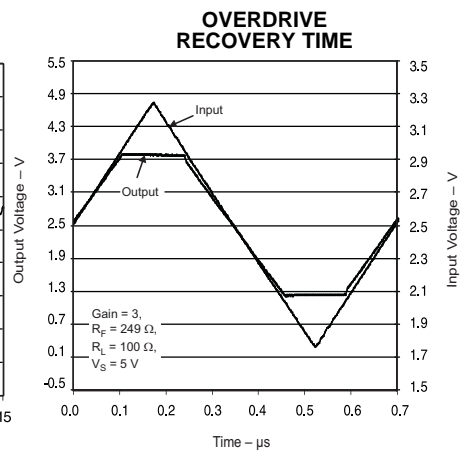


Figure 27.

TYPICAL CHARACTERISTICS (3 V)

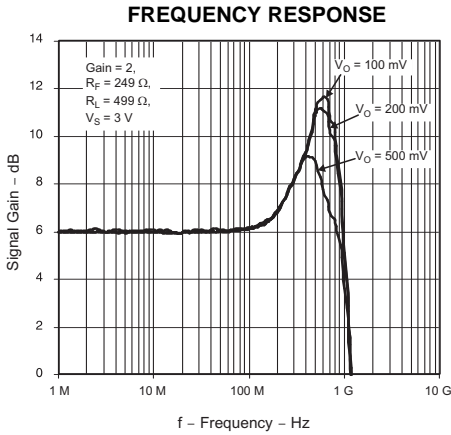


Figure 28.

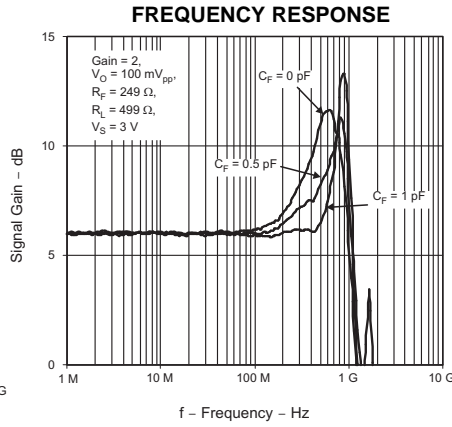


Figure 29.

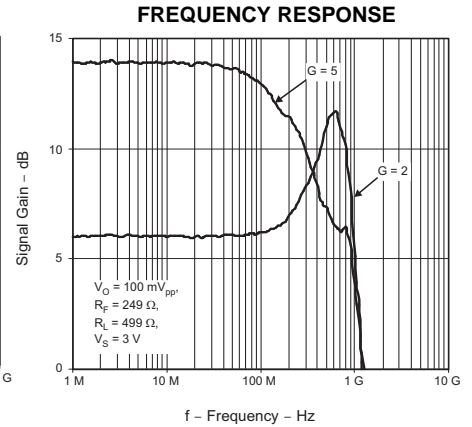


Figure 30.

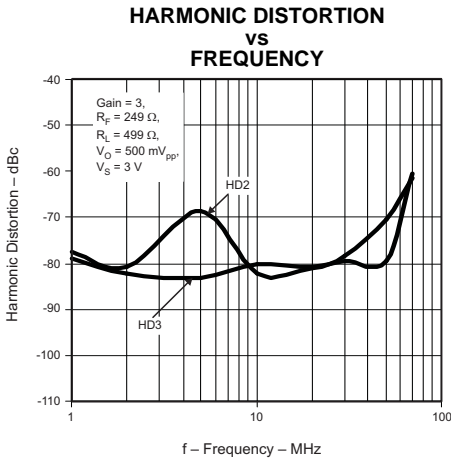


Figure 31.

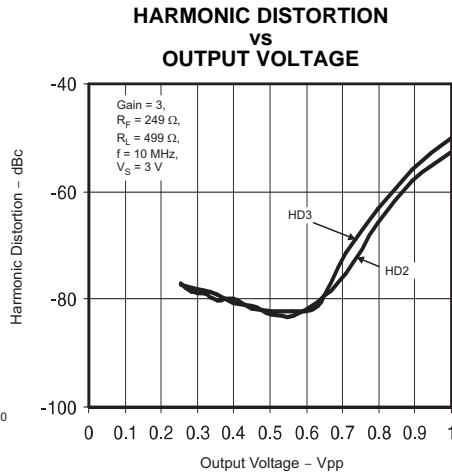


Figure 32.

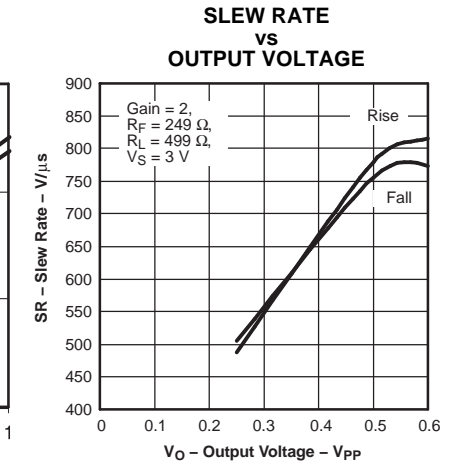


Figure 33.

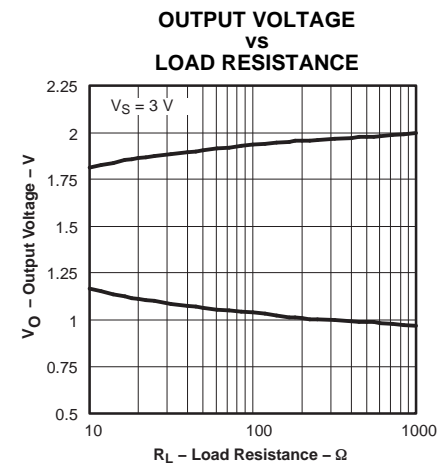


Figure 34.

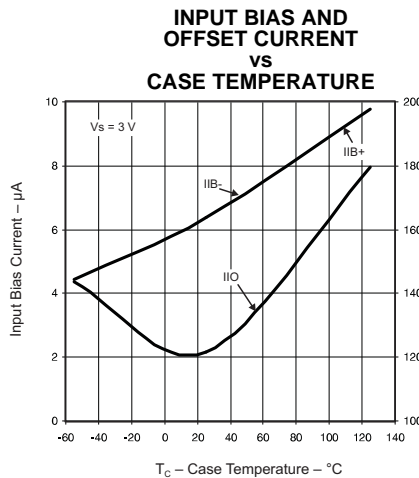


Figure 35.

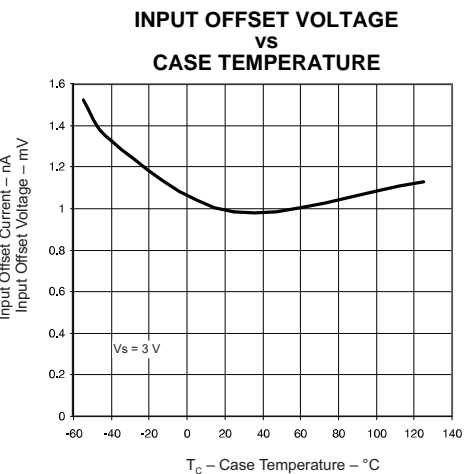


Figure 36.

APPLICATION INFORMATION

For many years, high-performance analog design has required the generation of split power supply voltages, like ± 15 V, ± 8 V, and more recently ± 5 V, to realize the full performance of the amplifiers available. Modern trends in high-performance analog are moving toward single-supply operation at 5 V, 3 V, and lower. This reduces power-supply cost due to less voltage being generated and conserves energy in low-power applications. It also can take a toll on available dynamic range, a valuable commodity in analog design, if the available voltage swing of the signal also must be reduced.

Two key figures of merit for dynamic range are signal-to-noise ratio (SNR) and spurious free dynamic range (SFDR).

SNR is simply the signal level divided by the noise:

$$\text{SNR} = \frac{\text{Signal}}{\text{Noise}}$$

and SFDR is the signal level divided by the highest spur:

$$\text{SFDR} = \frac{\text{Signal}}{\text{Spur}}$$

In an operational amplifier, reduced supply voltage typically results in reduced signal levels due to lower voltage available to operate the transistors within the amplifier. When noise and distortion remain constant, the result is a commensurate reduction in SNR and SFDR. To regain dynamic range, the process and the architecture used to make the operational amplifier must have superior noise and distortion performance with lower power supply overhead required for proper transistor operation.

The THS4304 BiCom3 operational amplifier is just such a device. It is able to provide 2 V_{pp} signal swing at its output on a single 5 V supply with noise and distortion performance similar to the best 10 V operational amplifiers on the market today

GENERAL APPLICATION

The THS4304 is a traditional voltage-feedback topology with wideband performance up to 1 GHz at a gain of 2 V/V. Care must be taken to ensure that parasitic elements do not erode the phase margin.

Capacitance at the output and inverting input, and resistance and inductance in the feedback path, can cause problems.

To reduce parasitic capacitance, the ground plane should be removed from under the part. To reduce inductance in the feedback, the circuit traces should be kept as short and direct as possible.

For a gain of +2V/V, it is recommended to use a 249 Ω feedback resistor. With good layout, this should keep the frequency response peaking to around 6 dB. This resistance is high enough to not load the output excessively, and the part is capable of driving 100 Ω load with good performance. Higher-value resistors can be used, with more peaking. Lower-value feedback resistors also can be used to reduce peaking, but degrade the distortion performance with heavy loads.

Power supply bypass capacitors are required for proper operation. The most critical are 0.1 μ F ceramic capacitors; these should be placed as close to the part as possible. Larger bulk capacitors can be shared with other components in the same area as the operational amplifier.

HARMONIC DISTORTION

For best second harmonic (HD₂), it is important to use a single-point ground between the power supply bypass capacitors when using a split supply. It also is recommended to use a single ground or reference point for input termination and gain-setting resistors (R₈ and R₁₁ in the non-inverting circuit). It is recommended to follow the EVM layout closely in your application.

EVALUATION MODULES

The THS4304 has two evaluation modules (EVMs) available. One is for the MSOP (DGK) package and the other for the SOT-23 (DBV) package. These provide a convenient platform for evaluating the performance of the part and building various different circuits. The full schematics, board layout, and bill of materials (as supplied) for the boards are shown in the following illustrations.

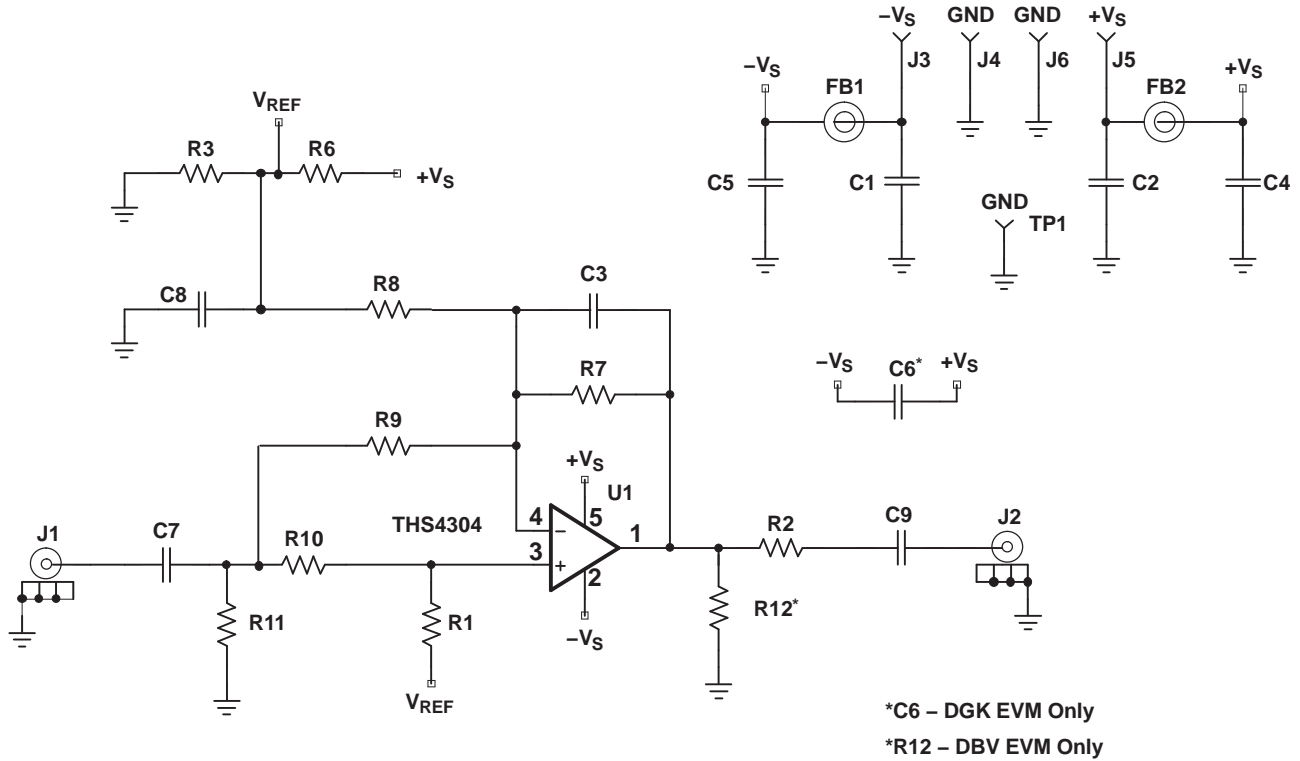


Figure 37. EVM Full Schematic

EVM BILL OF MATERIALS

| THS4304 EVM ⁽¹⁾ | | | | | | |
|----------------------------|---|----------|---------------------------------------|--------------|--|------------------------------|
| Item | Description | SMD Size | Reference Designator | PCB Quantity | Manufacturer's Part Number | Distributor's Part Number |
| 1 | Bead, ferrite, 3 A, 80 Ω | 1206 | FB1, FB2 | 2 | (STEWARD) HI1206N800R-00 | (DIGI-KEY) 240-1010-1-ND |
| 2 | Capacitor, 3.3 μF, Ceramic | 1206 | C1, C2 | 2 | (AVX) 1206YG335ZAT2A | (GARRETT) 1206YG335ZAT2A |
| 3 | Capacitor, 0.1 μF, Ceramic | 0603 | C4, C5 | 2 | (AVX) 0603YC104KAT2A | (GARRETT) 0603YC104KAT2A |
| 4 | Open | 0603 | C3, C6 ⁽²⁾ | 2 | | |
| 5 | Open | 0603 | R1, R3, R6, R9, R12 ⁽³⁾ | 5 | | |
| 6 | Resistor, 0 Ω, 1/10 W, 1% | 0603 | C7, C8, C9, C10 | 4 | (KOA) RK73Z1JTDD | (GARRETT) RK73Z1JTDD |
| 7 | Resistor, 49.9 Ω, 1/10 W, 1% | 0603 | R2, R11 | 2 | (KOA) RK73H1JLTD49R9F | (GARRETT) RK73H1JLTD49R9F |
| 8 | Resistor, 249 Ω, 1/10 W, 1% | 0603 | R7, R8 | 2 | (KOA) RK73H1JLTD2490F | (GARRETT) RK73H1JLTD2490F |
| 9 | Jack, banana receptacle, 0.25 in. diameter hole | | J3, J4, J5, J6 | 4 | (HH SMITH) 101 | (NEWARK) 35F865 |
| 10 | Test point, black | | TP1 | 1 | (KEYSTONE) 5001 | (DIGI-KEY) 5001K-ND |
| 11 | Connector, edge, SMA PCB jack | | J1, J2 | 2 | (JOHNSON) 142-0701-801 | (NEWARK) 90F2624 |
| 12 | Integrated Circuit, THS4304 | | U1 | 1 | (TI) THS4304DGK, or (TI) THS4304DBV | |
| 13 | Standoff, 4-40 HEX, 0.625 in. Length | | | 4 | (KEYSTONE) 1808 | NEWARK) 89F1934 |
| 14 | Screw, Phillips, 4-40, 0.250 in. | | | 4 | SHR-0440-016-SN | |
| 15 | Board, printed-circuit | | | 1 | (TI) THS4304DGK ENG A, or (TI) THS4304DBV ENG A | |

(1) NOTE: All items are designated for both the DBV and DGK EVMs unless otherwise noted.

(2) C6 used on DGK EVM only.

(3) R12 used on DBV EVM only.

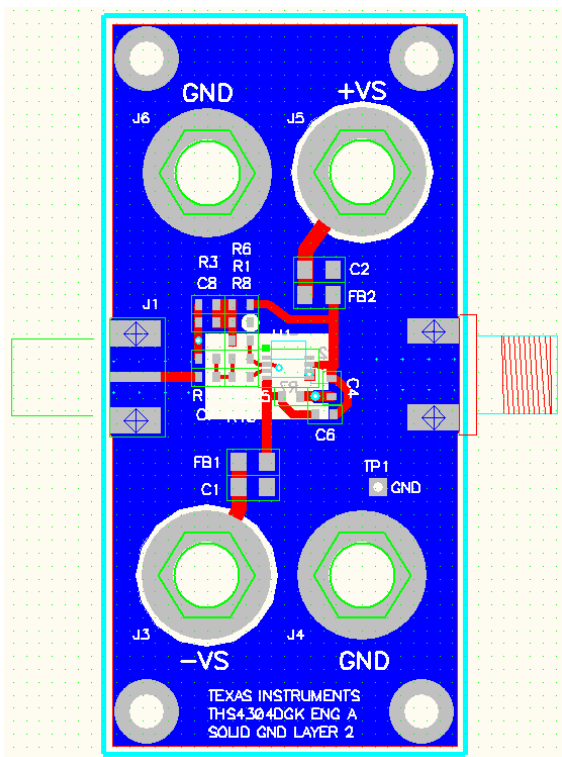


Figure 38. THS4304DGK EVM Layout Top and L2

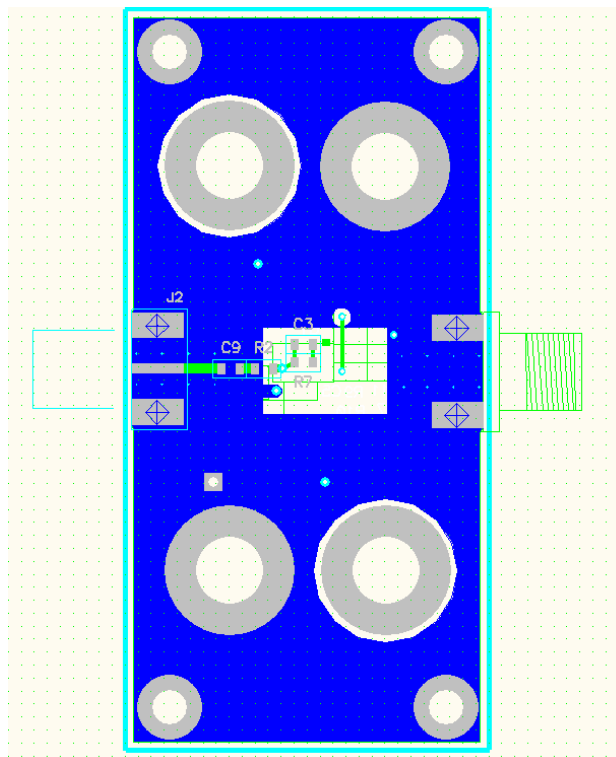


Figure 39. THS4304DGK EVM Layout Bottom and L3

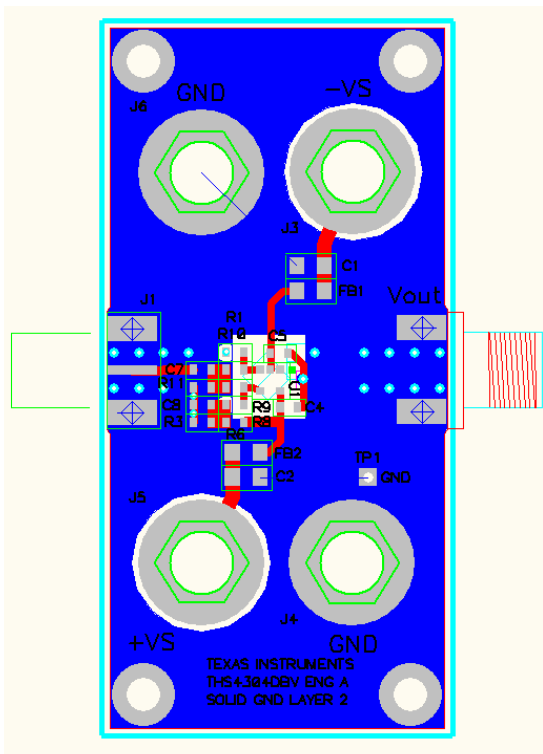


Figure 40. THS4304DBV EVM Layout Top and L2

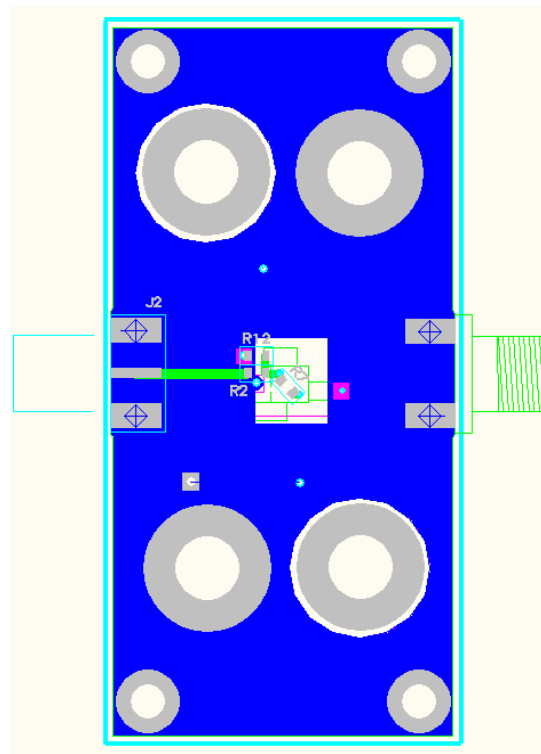


Figure 41. THS4304DBV EVM Layout Bottom and L3

NON-INVERTING GAIN WITH SPLIT SUPPLY

The following schematic shows how to configure the operational amplifier for non-inverting gain with split power supply ($\pm 2.5V$). This is how the EVM is supplied from TI. This configuration is convenient for test purposes because most signal generators and analyzer are designed to use ground-referenced signals by default. Note the input and output provides 50 Ω termination.

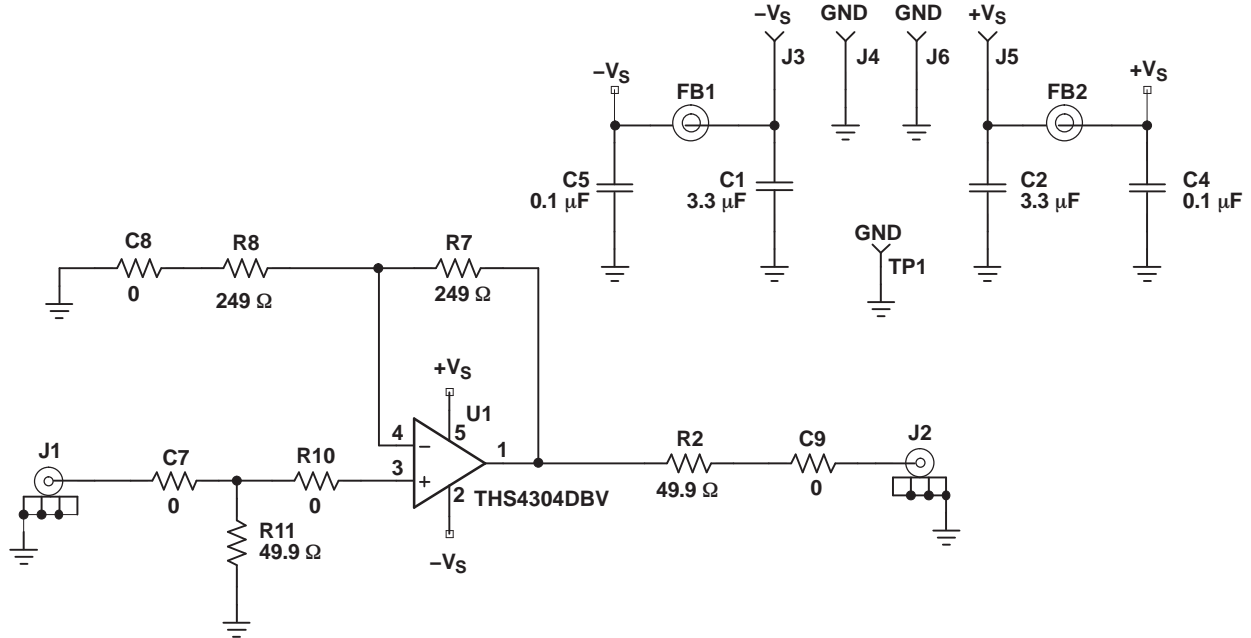


Figure 42. Non-Inverting Gain With Split Power Supply

INVERTING GAIN WITH SPLIT POWER SUPPLY

The following schematic shows how to configure the operational amplifier for inverting gain of 1 (-1 V/V) with split power supply (± 2.5 V). Note the input and output provides $50\ \Omega$ termination for convenient interface to common test equipment.

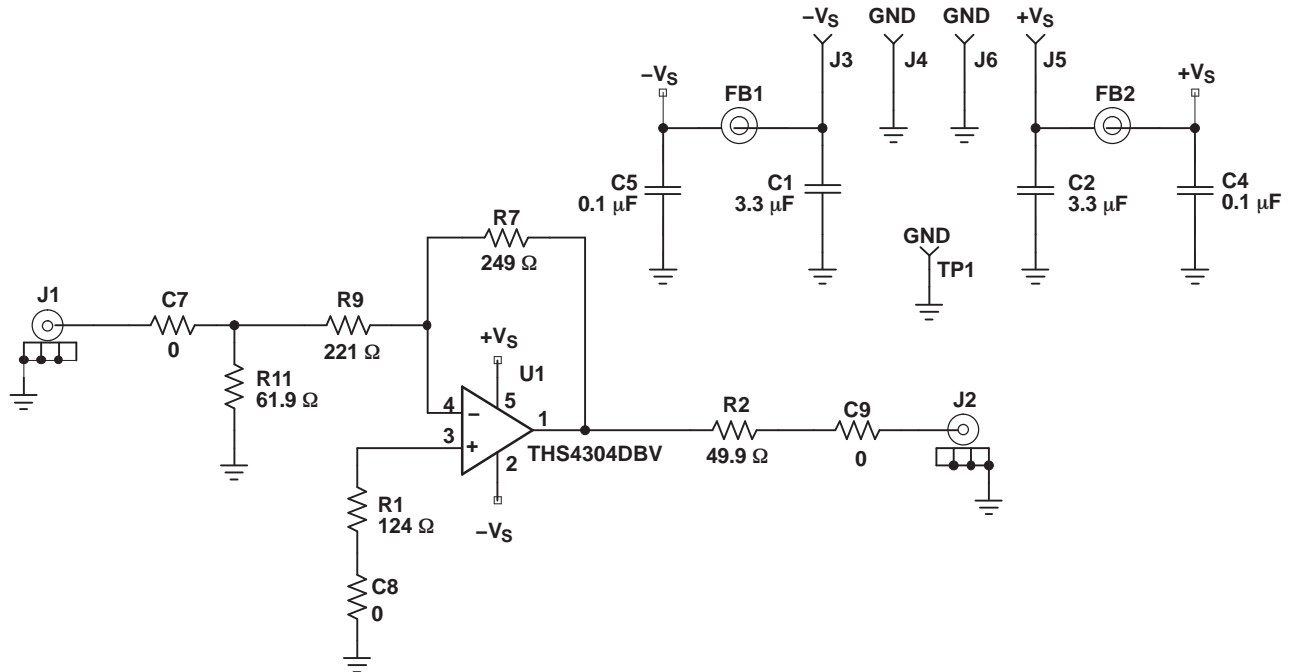


Figure 43. Inverting Gain With Split Power Supply

NON-INVERTING SINGLE-SUPPLY OPERATION

The THS4304 EVM can easily be configured for single 5 V supply operation, as shown in the following schematic, with no change in performance. This circuit passes dc signals at the input, so care must be taken to reference (or bias) the input signal to mid-supply.

If dc operation is not required, the amplifier can be ac coupled by inserting a capacitor in series with the input (C7) and output (C9).

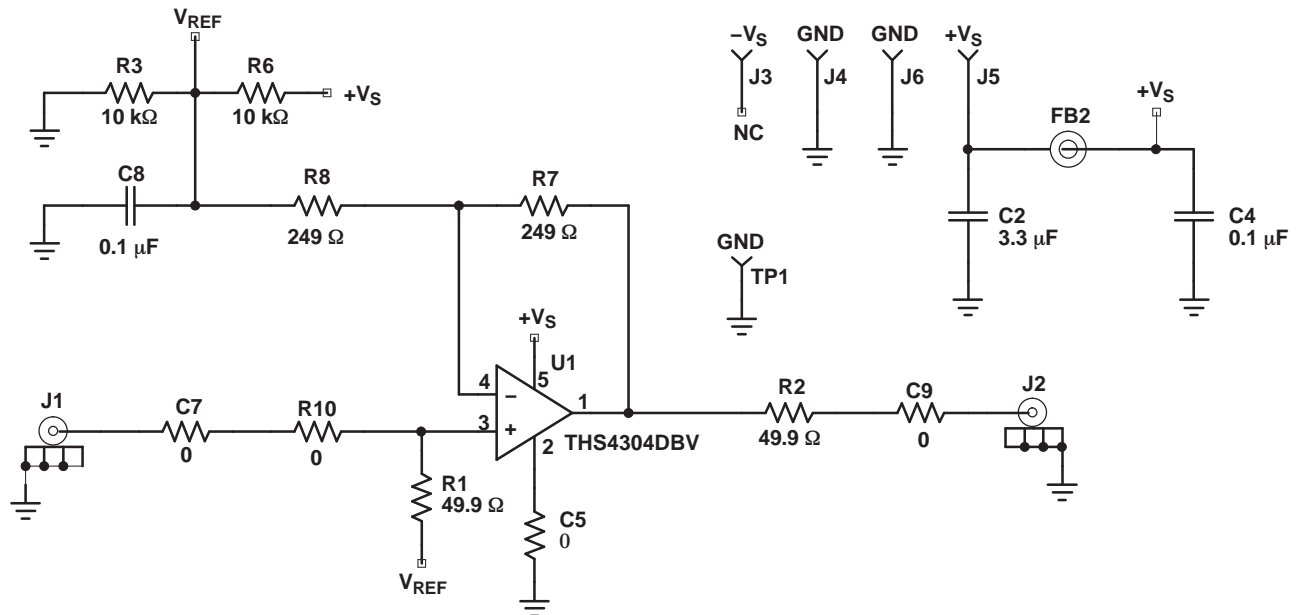


Figure 44. Non-Inverting 5-V Single-Supply Amplifier

DIFFERENTIAL ADC DRIVE AMPLIFIER

The circuit shown in Figure 44 is adapted as shown in Figure 45 to provide a high-performance differential amplifier drive circuit for use with high-performance ADCs, like the ADS5500 (14 bit 125 MSP ADC). For testing purposes, the circuit uses a transformer to convert the signal from a single-ended source to differential. If the input signal source in your application is differential and biased to mid-rail, no transformer is required.

The circuit employs two amplifiers to provide a differential signal path to the ADS5500. A resistor divider (two 10 kΩ resistors) is used to obtain a mid-supply reference voltage of 2.5 V (VREF) (the same as shown in the single-supply circuit of Figure 44). Applying this voltage to the one side of RG and to the positive input of the operational amplifier (via the center-tap of the transformer) sets the input and output common-mode voltage of the operational amplifiers to mid-rail to optimize their performance. The ADS5500 requires an input common-mode voltage of 1.5 V. Due to the mismatch in required common-mode voltage, the signal is ac coupled from the amplifier output, via the two 1 nF capacitors, to the input of the ADC. The CM voltage of the ADS5500 is used to bias the ADC input to the required voltage, via the 1 kΩ resistors. Note: 100 μA common-mode current is drawn by the ADS5500 input stage (at 125 MSPS). This causes a 100 mV shift in the input common-mode voltage, which does not impact the performance when driving the input to -1 dB of full scale. To offset this effect, a voltage divider from the power supply can be used to derive the input common-mode voltage reference.

Because the operational amplifiers are configured as non-inverting, the inputs are high impedance. This is particularly useful when interfacing to a high-impedance source. In this situation, the amplifiers provide impedance matching and amplification of the signal.

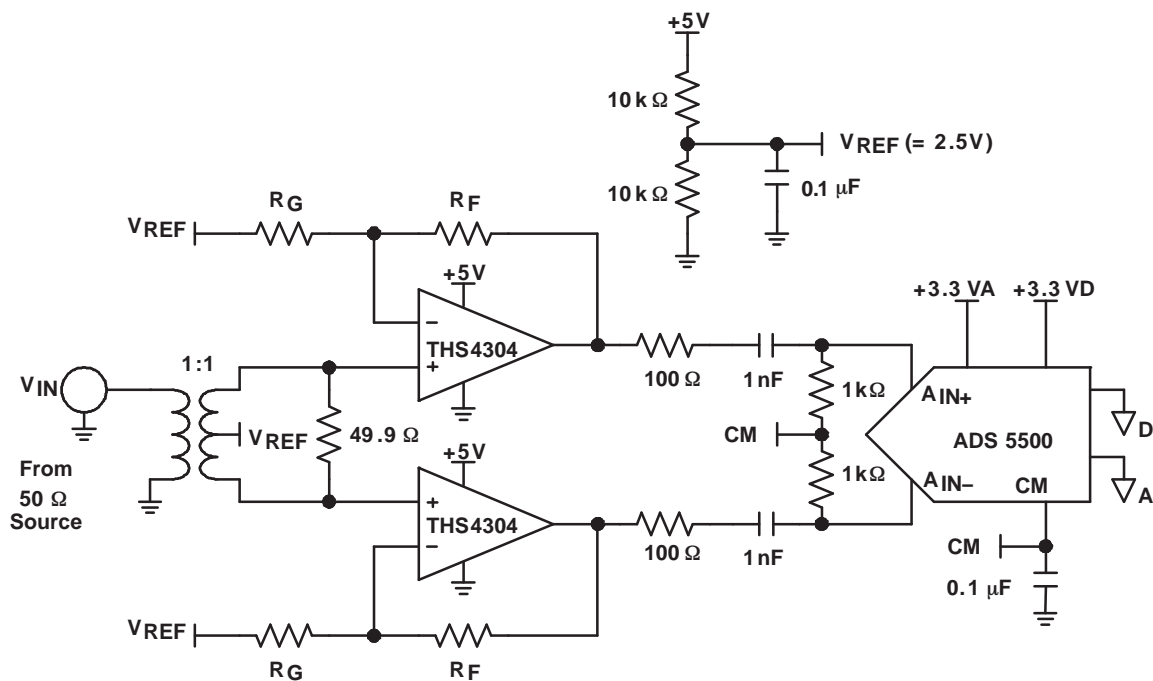


Figure 45. Differential ADC Drive Amplifier Circuit

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|------------------------|
| 5962-0721901VHA | Active | Production | CFP (HKK) 10 | 25 TUBE | No | AU | N/A for Pkg Type | -55 to 125 | 0721901VHA THS4304M |

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF THS4304-SP :

- Catalog : [THS4304](#)

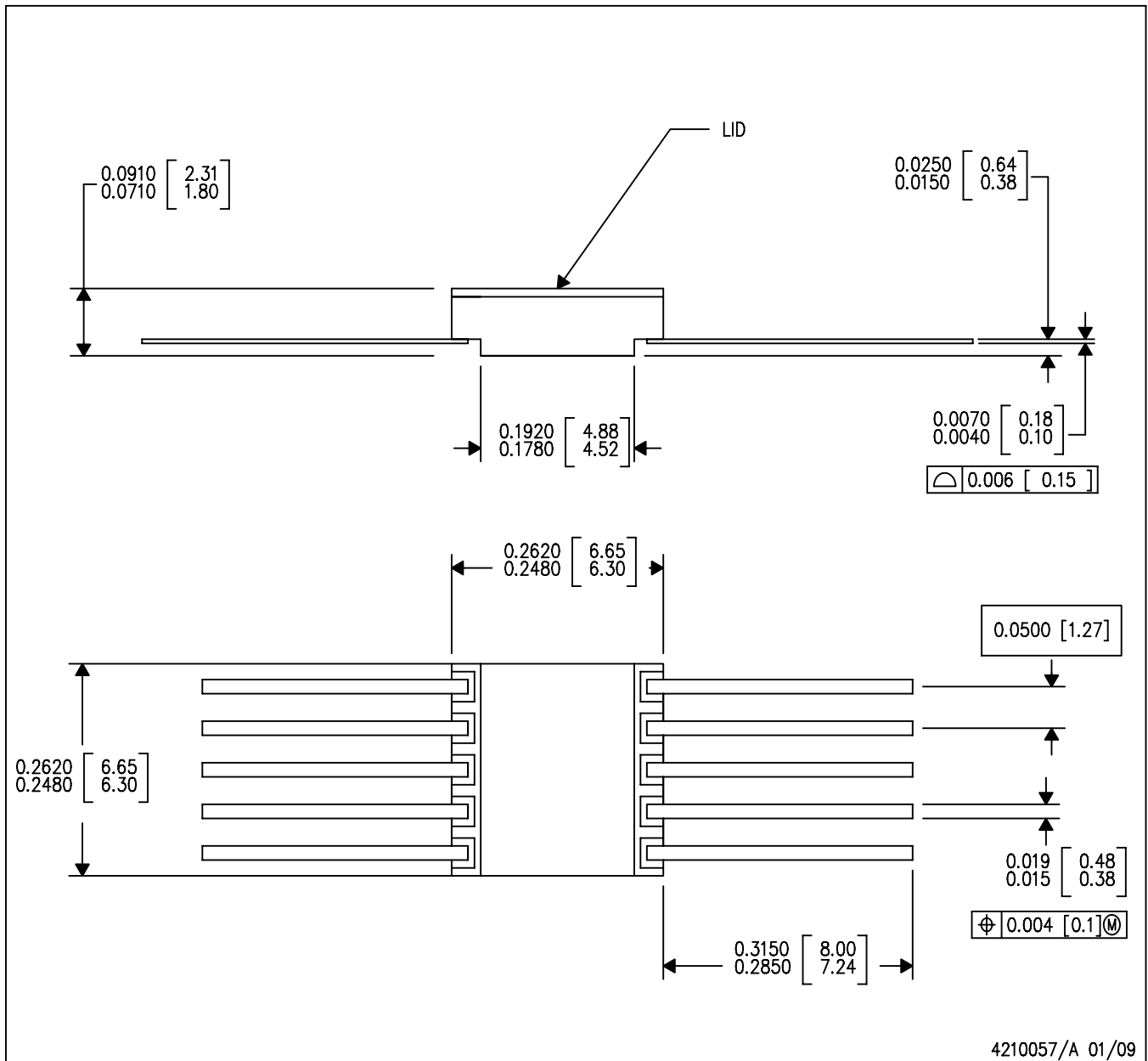
NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TUBE


*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| 5962-0721901VHA | HKK | CFP | 10 | 25 | 506.98 | 26.16 | 6220 | NA |



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This drawing does not comply with Mil Std 1835. Do not use this package for compliant product.
 - The terminals will be gold plated.

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Last updated 10/2025